# MSKSEMI















**ESD** 

TVS

TSS

MOV

**GDT** 

**PLED** 

# Brodnet data speet

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#### Semiconductor

#### Compiance

#### **Features**

Ideal for printed circuit board

Reliable low cost construction utilizing molded plastic technique

High temperature soldering guaranteed: 260°/10 seconds at 5

lbs., (2.3kg) tension

Small size, simple installation

High surge current capability

# .047(1.20) .035(0.9) .014(0.35) .008(0.20) .008(0.20)

### **Mechanical Data**

Case: JEDEC DBS Molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750, Method

2026

Polarity: Polarity symbol marking on case

Mounting Position: Any

Weight: 0.02 ounce, 0.4 grams

Dimensions in inches and (millimeters)

#### **REEL SPECIFICATION**

P/N	PKG	QTY
DB201S-DB207S	DBS	1500

# **Maximum Ratings And Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwisespecified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	UNITS
Marking Code		DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at T <sub>C</sub> =40°C		2.0					Α		
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		60					А		
Maximum instantaneous forward voltage drop per leg at 1A	VF	1.1				V			
Maximum DC reverse current T <sub>A</sub> =25°C at rated DC blocking voltage T <sub>A</sub> =100°C	lR	10 500					μA μA		
Operating temperature range	TJ	-55 to +150			°C				
storage temperature range	Тѕтс	-55 to +150			°C				

NOTES:DBS for surface mount package.



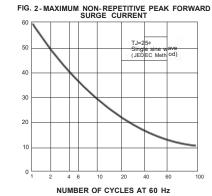
Semiconductor



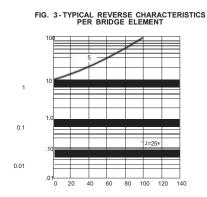
AVERAGE FORWARD CURRENT(A)

AMBIENT TEMPERATURE, © C

PEAK FORWARD CURRENT.(A)

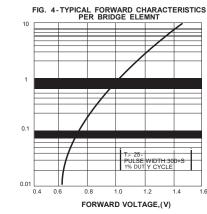


INSTANTANEOUS REVERSE CURRENT(\*A)

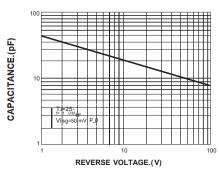


PERCENT OF RATED PEAK REVERSE VOLTAGE. (%)

INSTANTANEOUS REVERSE CURRENT.(A)









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